

MDL-N-808/7000~10000mW

INFRARED DIODE LASER AT 808nm





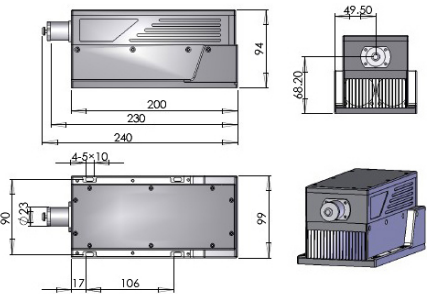
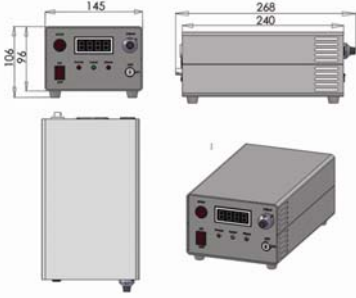
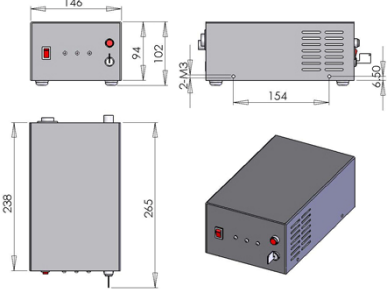
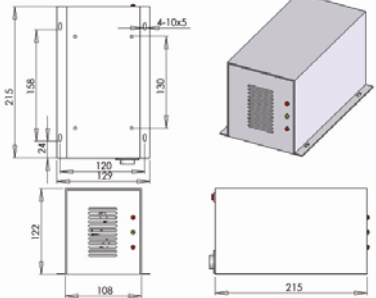
Diode infrared laser module at 808nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

| | | | |
|---|---|-----------|-----------|
| Wavelength (nm) | 808±3 | | |
| Output power (mW) | >7000, 7100, 7200, ... , 10000 | | |
| Transverse mode | Near TE ₀₀ | | |
| Operating mode | CW | | |
| Power stability (rms, over 4 hours) | <1%, <3%, <5% | | |
| Warm-up time (minutes) | <5 | | |
| M ² factor | <20 | | |
| Beam divergence, full angle (mrad) | <3.0 | | |
| Beam diameter at the aperture (mm) | 5~8 | | |
| Beam height from base plate (mm) | 68.2 | | |
| Pointing stability after warm-up (mrad) | <0.05 | | |
| Operating temperature (°C) | 10~35 | | |
| Power supply (90-264VAC) | PSU-H-LED | PSU-H-FDA | PSU-N-OEM |
| Modulation option | TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off | | |
| Expected lifetime (hours) | 10000 | | |
| Warranty period | 1 year | | |



| MDL-N-808 | PSU-H-LED | PSU-H-FDA | PSU-N-OEM |
|---|---|---|--|
|  <p>240(L)×99(W)×94(H) mm³, 2.6 kg</p> |  <p>268 (L) ×145(W) ×106 (H) mm³, 2.6 kg</p> |  <p>238 (L) ×146(W) ×102 (H) mm³, 2.3 kg</p> |  <p>215 (L) ×129 (W) ×122 (H) mm³, 2.145 kg</p> |
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